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January 2007

## FDY300NZ

### Single N-Channel 2.5V Specified PowerTrench® MOSFET

#### **General Description**

This Single N-Channel MOSFET has been designed using Fairchild Semiconductor's advanced Power Trench process to optimize the  $R_{\text{DS(ON)}} @\ V_{\text{GS}} = 2.5 \text{v}.$ 

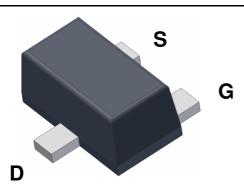
#### **Applications**

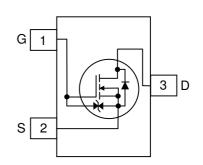
• Li-Ion Battery Pack



#### **Features**

- 600 mA, 20 V  $R_{DS(ON)}=$  700 m $\Omega$  @  $V_{GS}=$  4.5 V  $R_{DS(ON)}=$  850 m $\Omega$  @  $V_{GS}=$  2.5 V
- ESD protection diode (note 3)
- RoHS Compliant





#### Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter	Ratings	Unit s
$V_{DSS}$	Drain-Source Voltage	20	V
$V_{GSS}$	Gate-Source Voltage	± 12	V
I <sub>D</sub>	Drain Current - Continuous (Note 1a)	(a) 600	mA
	<ul><li>Pulsed</li></ul>	1000	
P <sub>D</sub>	Power Dissipation (Steady State) (Note 1a)	(a) 625	mW
	(Note 1b)	446	
$T_J$ , $T_{STG}$	Operating and Storage Junction Temperature Range	-55 to +150	°C

#### **Thermal Characteristics**

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 1a)	la) 200	°C/W
Reja	Thermal Resistance, Junction-to-Ambient (Note 1b)	280	

**Package Marking and Ordering Information** 

Device Marking	Device	Reel Size	Tape width	Quantity
С	FDY300NZ	7 "	8 mm	3000 units

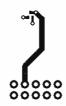
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS}=0~V, \qquad I_D=250~\mu A$	20			V
<u>ΔBV<sub>DSS</sub></u> ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D$ = 250 $\mu$ A, Referenced to 25°C		15		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 16 \text{ V}, \qquad V_{GS} = 0 \text{ V}$			1	μΑ
I <sub>GSS</sub>	Gate-Body Leakage,	$V_{GS} = \pm 12 \text{ V},  V_{DS} = 0 \text{ V}$ $V_{GS} = \pm 4.5 \text{ V},  V_{DS} = 0 \text{ V}$			± 10	μA μA
On Chara	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$	0.6	1.0	1.3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D$ = 250 $\mu$ A, Referenced to 25°C		3		mV/°C
$R_{DS(on)}$	Static Drain–Source On–Resistance	$\begin{array}{l} V_{GS} = 4.5 \text{ V}, & I_D = 600 \text{ mA} \\ V_{GS} = 2.5 \text{ V}, & I_D = 500 \text{ mA} \\ V_{GS} = 1.8 \text{ V}, & I_D = 150 \text{ mA} \\ V_{GS} = 4.5 \text{ V}, & I_D = 600 \text{mA}, & T_J = 125 ^{\circ}\text{C} \end{array}$		0.24 0.36 0.70 0.35	0.70 0.85 1.25 1.00	Ω
<b>g</b> FS	Forward Transconductance	$V_{DS} = 5 \text{ V}, \qquad I_{D} = 600 \text{ mA}$		1.8		S
Dynamic	Characteristics					
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 10 \text{ V},  V_{GS} = 0 \text{ V},$		60		pF
Coss	Output Capacitance	f = 1.0 MHz		20		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			10		pF
Switchin	g Characteristics (Note 2)					
t <sub>d(on)</sub>	Turn-On Delay Time	$ \begin{aligned} V_{DD} &= 10 \ V, & I_D &= 1 \ A, \\ V_{GS} &= 4.5 \ V, & R_{GEN} &= 6 \ \Omega \end{aligned} $		6	12	ns
t <sub>r</sub>	Turn-On Rise Time			8	16	ns
$t_{d(off)}$	Turn-Off Delay Time	]		8	16	ns
t <sub>f</sub>	Turn-Off Fall Time			2.4	4.8	ns
$Q_g$	Total Gate Charge	$V_{DS} = 10 \text{ V}, \qquad I_{D} = 600 \text{ mA},$		0.8	1.1	nC
Q <sub>gs</sub>	Gate-Source Charge	$V_{GS} = 4.5 \text{ V}$		0.16		nC
$Q_{gd}$	Gate-Drain Charge	1		0.26		nC
Drain-Sc	ource Diode Characteristics	and Maximum Ratings				
V <sub>SD</sub>	Drain-Source Diode Forward Voltage	$V_{GS} = 0 \text{ V},  I_S = 150 \text{ mA} \text{ (Note 2)}$		0.7	1.2	V
t <sub>rr</sub>	Diode Reverse Recovery Time	I <sub>F</sub> = 600 mA,		8		nS
Qrr	Diode Reverse Recovery Charge	$dI_F/dt = 100 A/\mu s$		1		nC

#### Notes:

<sup>1.</sup> R<sub>BJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>BJC</sub> is guaranteed by design while R<sub>BCA</sub> is determined by the user's board design.



a) 200 °C/W when mounted on a 1in² pad of 2 oz copper



- b) 280 °C/W when mounted on a minimum pad of 2 oz copper Scale 1 : 1 on letter size paper
- 2. Pulse Test: Pulse Width < 300μs, Duty Cycle < 2.0%
- The diode connected between the gate and source serves only as protection againts ESD. No gate overvoltage rating is implied.

#### **Typical Characteristics**

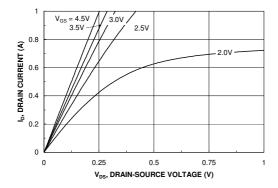


Figure 1. On-Region Characteristics.

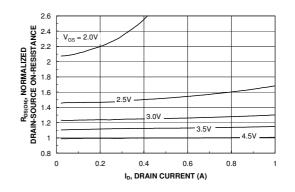


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

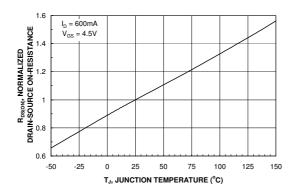


Figure 3. On-Resistance Variation with Temperature.

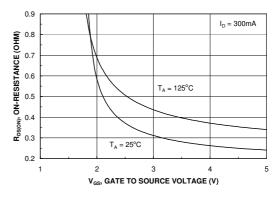


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

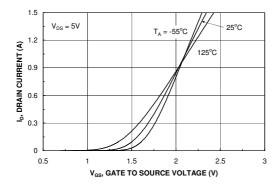


Figure 5. Transfer Characteristics.

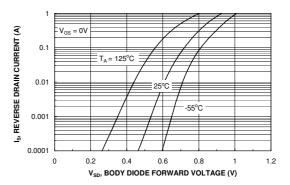
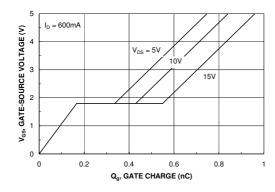


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

#### **Typical Characteristics**



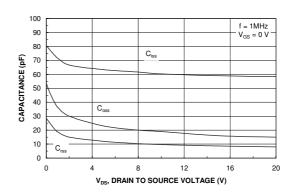
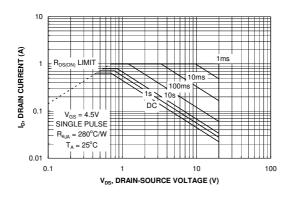


Figure 7. Gate Charge Characteristics.





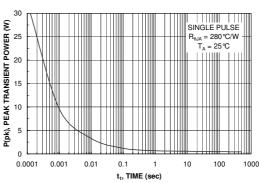


Figure 9. Maximum Safe Operating Area.

Figure 10. Single Pulse Maximum Power Dissipation.

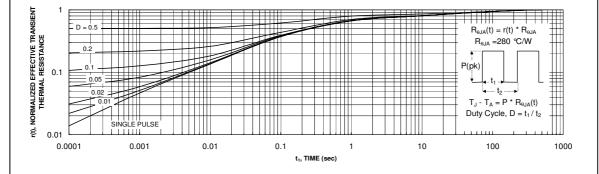
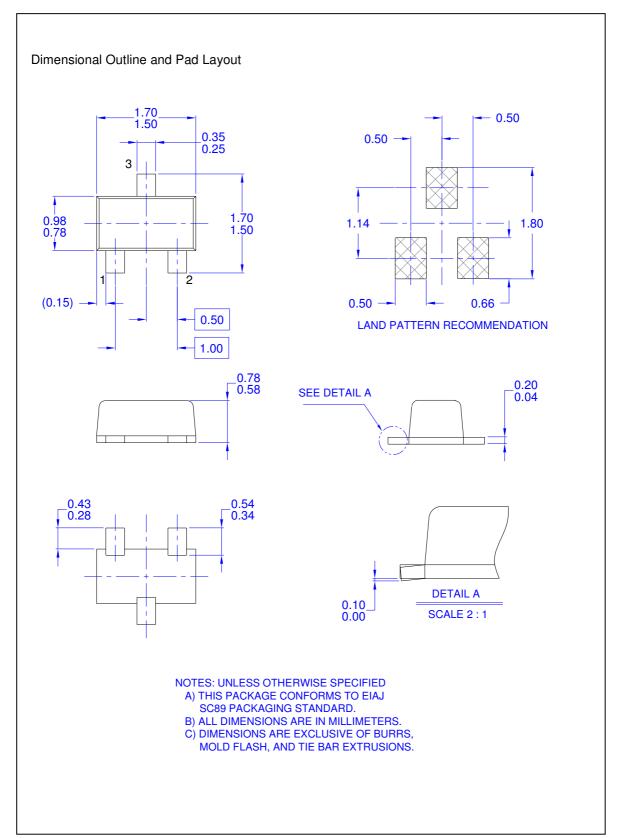


Figure 11. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1b. Transient thermal response will change depending on the circuit board design.



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